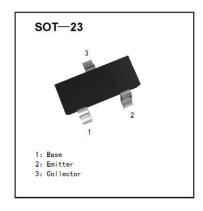


## NPN Silicon Epitaxial Planar Transistor

for switching and AF amplifier applications.

The transistor is subdivided into four groups O, Y, G and L, according to its DC current gain. As complementary type the PNP transistor



## ● Absolute Maximum Ratings (T<sub>a</sub> = 25 °C)

Parameter	Symbol	Value	Unit	
Collector Base Voltage	V <sub>CBO</sub>	60	V	
Collector Emitter Voltage	V <sub>CEO</sub>	50	V	
Emitter Base Voltage	V <sub>EBO</sub>	5	V	
Collector Current	Ic	150	mA	
Base Current	I <sub>B</sub>	50	mA	
Power Dissipation	P <sub>tot</sub>	200	mW	
Junction Temperature	Tj	150	°C	
Storage Temperature Range	T <sub>S</sub>	-55 to +150	°C	

## ● Characteristics at T<sub>amb</sub>=25 °C

Parameter		Symbol	Min.	Тур.	Max.	Unit
DC Current Gain at V <sub>CF</sub> =6V, I <sub>C</sub> =2mA						
Current Gain Group	0	h <sub>FE</sub>	70	:=	140	-
	Υ	h <sub>FE</sub>	120	12	240	-
	G	h <sub>FE</sub>	200	1.00	400	-
at $V_{CE}$ =6V, $I_{C}$ =150mA	L	h <sub>FE</sub> h <sub>FE</sub>	350 25	-	700	-
Collector Saturation Voltage at I <sub>C</sub> =100mA, I <sub>B</sub> =10mA		V <sub>CE(sat)</sub>	-	-	0.25	V
Base Saturation Voltage at $I_C$ =100mA, $I_B$ =10mA		V <sub>BE(sat)</sub>	•	-	1	V
Collector Cutoff Current at $V_{CB}$ =60V at $V_{EB}$ =5V		I <sub>CBO</sub>		-	0.1 0.1	μA μA
Gain Bandwidth Product at V <sub>CE</sub> =10V, I <sub>C</sub> =1mA		f <sub>T</sub>	80	75	-	MHz
Output Capacitance at V <sub>CB</sub> =10V, f=1MHz		C <sub>OB</sub>		2	3	pF
Noise Figure at $V_{CE}$ =6 $V$ , $I_{C}$ =0.1 $m$ A, f=1 $K$ Hz, $R_{G}$ =10 $K$ $\Omega$		NF	-	1	1	dB



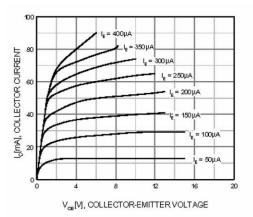


Figure 1. Static Characteristic

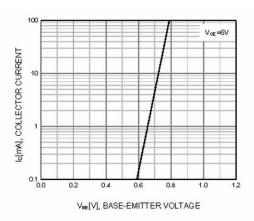


Figure 2. Transfer Characteristic

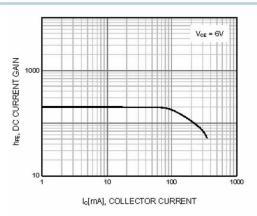


Figure 3. DC current Gain

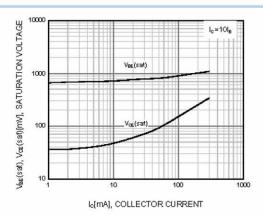


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

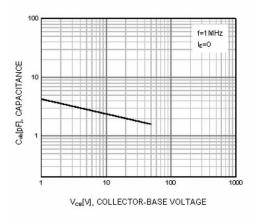


Figure 5. Output Capacitance

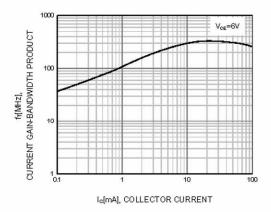


Figure 6. Current Gain Bandwidth Product

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